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Discrimination of quantum dots using an optically created nuclear field

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We investigated an optically created nuclear field in a single InAlAs quantum dot and demonstrated that the nuclear field can be used to discriminate whether photoluminescence lines originate from the same dot or a different dot. Since the nonlinear response of the nuclear field is sensitive to the electron g factor and correlation time of a coupled electron-nuclear spin system, the resultant Overhauser shift is their good measure for individual quantum dots. This method provides a simple and convenient alternative to the standard photon cross-correlation method. © 2008 American Institute of Physics. [DOI: 10.1063/1.2839615]

Single quantum dot (QD) devices attract considerable attention in the field of semiconductor nanostructures because of their potential for single photon emission, single electron storage, and manipulation of single qubits for quantum information processing. Therefore, single QD spectroscopy plays an increasingly important role of exploring and controlling these properties. In general, many photoluminescence (PL) lines are observed even for a truly single QD since exciton complexes such as neutral biexciton, positively, and negatively charged excitons are generated under the usual excitation conditions. Further, when several QDs exist in the measurement area, e.g., in a single mesa structure, PL lines of the exciton families from other QDs also emerge. In the standard spectroscopic procedure, we need to assign the origins of the observed PL lines. By various measurements for the assignments, it is possible to clarify the origin of an individual PL line; however, the procedure to achieve this is cumbersome. Primarily, it is necessary to discriminate whether the emissions originate from the same single QD or a different QD. This can be achieved by a photo cross-correlation measurement using a Hanbury–Brown and Twiss (HBT) setup or by single QD selection from a microimage of the emissions using a pinhole. These methods are very effective, however, HBT measurement generally requires care and takes a long time because of large photon loss, and QD selection through a pinhole is effective only in case of single-stacked QDs.

Recently, research on electron-nuclear spin interaction has been revived considering its applications. Because semiconductor QDs enhance the electron-nuclear spin exchange interaction (hyperfine interaction) due to the strong three-dimensional confinement of the electron wavefunction, and the enhanced interaction allows the possibility of aligning nuclear spins in one direction up to several tens of percentage in a single QD through optical pumping. In fact, a high rate of nuclear spin polarization and the resultant large effective nuclear field up to several tesla were recently observed in interface GaAs QDs, self-assembled InAlAs QDs, and InGaAs QDs. Because of the ultralong coherence, nuclear spin is expected to contribute to applications such as a long-lived quantum memory at the nuclear level and qubit conversion using a nuclear field. Apart from such potential applications for quantum information processing, the nuclear field is also useful for the evaluation of the magnitude and sign of an electron and hole g factors, which is based on the fact that a nuclear field affects only electrons and can compensate for the external magnetic field. In this study, we demonstrate a simple discrimination method of PL originating from individual QDs. This method is based on the sensitivity of the optically created nuclear field for individual QDs to the electron g factor, the electron spin coherence, etc.

The sample used here was In0.75Al0.25As QDs grown on a Al0.3Ga0.7As/GaAs buffer layer on an undoped (100) GaAs substrate by molecular beam epitaxy: density $\sim5 \times 10^{10}$ cm$^{-2}$, diameter $\sim20$ nm, and height $\sim3$ nm. A small mesa structure with a typical top lateral diameter of $\sim150$ nm was fabricated to limit the observable QDs. On the average, there are several QDs in a mesa; however, some mesas only have one or a few QDs due to inhomogeneous QD distribution, in which well-separated sharp QD emissions are observed. The micro-PL measurements were performed at 5 K under the longitudinal external magnetic field $B_z$ up to 5 T in a Faraday configuration. A cw-Ti:sapphire laser beam traveling along the QD growth direction was focused on the sample surface using a microscope objective. The QD emissions collected by the same objective lens were dispersed using a triple grating spectrometer and detected using a liquid N$_2$-cooled Si-charge-coupled device (CCD) camera. The spectral resolution that determines the resonant peak energies was $\sim5$ $\mu$eV, measured by the spectral fitting. The typical exposure time of the CCD camera to obtain one spectrum with a high signal-to-noise ratio was 1 s.

Figure 1(a) shows the PL spectra of the InAlAs QDs in a single mesa structure at 5 K and 0 T. The sample was excited at the wetting layer ($\sim1.698$ eV) by a linearly polarized light. The five PL peaks labeled as P1–P5 are observed clearly in this energy region. Figure 1(b) shows the application of $B_z$ results in the Zeeman splitting of each peak with a blueshift due to a diamagnetic effect. Figure 1(b) also shows...
the contour plot of the PL intensity at $B_z=4$ T as a function of the degree of circular polarization of the excitation light. The PL spectra were obtained by rotating the angle $\theta_{\text{QWP}}$ of a quarter-wave plate (QWP) inserted in the excitation beam path. $\theta_{\text{QWP}}=0$, $0.25\pi$, and $+0.25\pi$ correspond to the $\sigma_+$, $x$, $\sigma_-$, and $y$ polarized excitations, respectively. The difference in Zeeman energy is observed with linearly polarized wavefunction in a QD:10–12

\begin{equation}
\frac{1}{T_{\text{NF}}} = \tau_\sigma \left( \frac{A}{g} \right)^2 \left[ 1 + \left( \frac{\tau_\sigma}{\hbar} \right)^2 \left( g^c \mu_B (B_z \pm B_N) \right)^2 \right],
\end{equation}

where $\langle S_z \rangle$ is the averaged electron spin polarization, $S_0$ is the thermal electron spin polarization, $1/T_{\text{NF}}$ and $1/T_{\text{ND}}$ are the nuclear spin polarization and depolarization rates, respectively, and $Q = [I(1+1)]/[S(S+1)]$ is a momentum conversion coefficient from electron spin to nuclear spin system in the spin flip-flop process. Based on the general form of the spin-flip process of the precessional decoherence type,19 the spin transfer rate $1/T_{\text{NF}}$ is expressed as follows by assuming uniform electron wavefunction in a QD:10–12

\begin{equation}
d(I)\,dt = [Q(\langle S_z \rangle - S_0) - \langle I \rangle] / T_{\text{NF}} - \langle I \rangle / T_{\text{ND}},
\end{equation}

The steady state $\langle I \rangle$ is determined by the balance between the nuclear spin polarization and its depolarization, as shown in the following rate equation:19,20

\begin{figure}[h]
\centering
\includegraphics[width=\textwidth]{fig1.png}
\caption{(Color online) (a) PL spectra recorded at $B_z=0$ T for an excitation wavelength of $\sim 730$ nm. (b) A CCD image of the Zeeman-split PL lines at $B_z=4$ T as a function of the rotating angle of QWP ($\theta_{\text{QWP}}$) that was inserted in an excitation path. $\theta_{\text{QWP}}=0$, $0$, $0.25\pi$, and $0.5\pi$ correspond to the $\sigma_+$, $x$, $\sigma_-$, and $y$ polarized excitations, respectively.}
\end{figure}

\begin{figure}[h]
\centering
\includegraphics[width=\textwidth]{fig2.png}
\caption{(Color online) [(a) and (b)] Zeeman splitting of P1–P5 as a function of $\theta_{\text{QWP}}$ at $B_z=4$ and 5 T, respectively. Under the same excitation conditions, the OHSs are clearly different between the groups I (P1 and P2) and II (P3–P5). Solid curves are calculated by Eqs. (1) and (2) using $g^c(0)=0.42$, $g^c(\pi)=0.34$, $g^e=18.8$ ps, $g^e=38.7$ ps, $f=0.2$, $N^0=28000$, $N^N=44000$, and $A=52.6$ $\mu$eV. Dashed curve indicates the hysteretic behavior in the $\langle S_z \rangle$ dependence of the Overhauser shift calculated with the same parameters of group II.}
\end{figure}
tation polarization and power.\textsuperscript{11} The significantly asymmetrical OHS and the abrupt change of OHS prove the validity of the above-mentioned formation mechanism of the nuclear spin polarizations: the explosive increase of the spin transfer rate of Eq. (2) for $B_z - B_N \sim 0$. Further, the positive abrupt change of OHS clearly shows that the electron and hole g factors have opposite signs. $g^e_z g^h_b > 0$. If $g^e_z g^h_b < 0$, the observed total Zeeman splitting is the sum of the electron and hole Zeeman splitting and, therefore, it decreases due to the reduced electron Zeeman splitting when $B_z$ is compensated by $B_N$, as in the case of In(Ga)As QDs. In fact, we evaluated $g^e_z|_{\text{BN}} = +2.52 \pm 0.01$ and $g^h_b|_{\text{BN}} = -0.42 \pm 0.02$ for group I and $g^e_z|_{\text{II}} = +2.36 \pm 0.01$ and $g^h_b|_{\text{II}} = -0.34 \pm 0.02$ for group II by canceling $B_N$ with $B_N$ at one edge of the nuclear spin bistability.\textsuperscript{15}

From the slope of the change around $\theta_{\text{OHP}} = 0.15 \pi$ and the maximum OHS around $\theta_{\text{OHP}} = 0.25 \pi$, groups I and II are found to be affected by the different nuclear fields. Considering the difference of the electron g factor, the maximum $B_N$'s observed in two groups are deduced: $B_N^{(1)} \sim -4.88$ T and $B_N^{(II)} \sim -4.66$ T. Besides, the short correlation time induces a slow change of the nuclear field because $h/\tau_z$ hinders the explosive increase of the spin transfer rate of Eq. (2) at $B_z - B_N \sim 0$. Therefore, the observed slope of the change around $\theta_{\text{OHP}} = 0.15 \pi$ is affected by the difference of $\tau_z$ for the two groups. In fact, the spectral width of group I is larger than that of group II: P2 (1.608 36 eV, 70 $\mu$eV) and P5 (1.616 94 eV, 34 $\mu$eV). At $B_z = 5$ T, the difference between the two groups stands out; the abrupt change of OHS disappears for group II, while group I still shows the asymmetric OHS. This difference can be explained by the change of the critical value of $B_z$ for the bistable behavior in the $B_z$-dependence.\textsuperscript{15} The critical value of $B_z$ for the abrupt change is sensitive to the QD properties; $g^e_z$ and $\tau_z$ under the same $B_z$. Therefore, above QD properties mainly determine the presence or absence of the abrupt change of OHS.

To confirm the above scenario, we reproduce the $\langle S_z \rangle$-dependence of OHS compared with the experimental results using Eqs. (1) and (2). The sweep direction of $\langle S_z \rangle$ from $-0.5 \theta_{\text{OHP}} = -0.25 \pi$ to $-0.5 (0.75 \pi)$ via $0.5 (0.25 \pi)$ is associated with the measurement conditions. In particular, the OHS of group II at $B_z \approx 4$ T shows a clear hysteresis behavior in the $\langle S_z \rangle$-dependence, that is, the OHS exhibits sweep direction dependence of $\langle S_z \rangle$ from $-0.5 \theta_{\text{OHP}} = -0.25 \pi$ to $0.5 (0.25 \pi)$ and $0.5 (0.25 \pi)$ to $-0.5 (0.75 \pi)$. This hysteresis in the $\langle S_z \rangle$ dependence has already been observed in the previous studies\textsuperscript{9,10} and is consistent with the physics of nuclear spin switching that has been recently reported.\textsuperscript{11} We show the calculation curves of OHS in Fig. 2 considering the hysteresis behavior. Assuming that $\tau_z$ is deduced by the coherence time of electron spin, we evaluated $\tau_z^{(1)} \sim 18.8$ ps for group I and $\tau_z^{(II)} \sim 38.7$ ps for group II by the spectra widths of P2 and P5, which are assigned to positively charged excitons. These values are consistent with the observed correlation time obtained by Fourier spectroscopy.\textsuperscript{17} The following parameters are used for reproduction of the experimental results: $A \sim 52.6 \mu$eV, $f \sim 0.21$, $T_{\text{ND}} \sim 50$ ms, $I(I+1) = 12.25$, $N^{(I)} = 28,000$, and $N^{(II)} = 44,000$, where $A$ and $I(I+1)$ are weighted values for an In$_{0.75}$Al$_{0.25}$As QD.\textsuperscript{22} Although the difference of $g^e_z$ and $\tau_z$ between the two groups is expected to be negligible because the differences in the emission energies are small (~8 meV), we observed great divergence in the nuclear field formation, implying that the shape and composition and strain of each QD are unique. The sensitivity of QD properties to the critical value of $B_z$ for the abrupt change of OHS facilitates a solution to discriminate the individual QDs.

We investigated the nuclear spin switching in InAlAs QDs and compared the behaviors in two different single QDs. The observed threshold value for the nuclear spin switching is found to be sensitive to the QD properties and, therefore, the switching is useful to discriminate the individual QDs in the same measurement area. This method provides a simple and convenient alternative to the standard photon cross-correlation method.

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\textsuperscript{22}A. Abragam, \textit{The Principles of Nuclear Magnetism} (Clarendon, Oxford, 1961), Chap. 6.
\textsuperscript{23}We assume that $f$ for the two groups are constant because in-plane distribution of excitation power around mesa structure (~150 nm) is less than ~5%.
\textsuperscript{24}P. Raghavan, At. Data Nucl. Data Tables \textbf{42}, 189 (1989).